

LM2904-Q1, LM2904B-Q1, and LM2904BA-Q1 Industry-Standard Dual Operational Amplifiers for Automotive Applications

1 Features

- AEC Q-100 qualified for automotive applications
 - Temperature grade 1: –40°C to +125°C
 - Device HBM ESD classification 2
 - Device CDM ESD classification C5
- Wide supply range of 3 V to 36 V (LM2904B-Q1 and LM2904BA-Q1)
- Supply-current of 300 µA per channel (LM2904B-Q1 and LM2904BA-Q1, typical)
- Unity-gain bandwidth of 1.2 MHz (LM2904B-Q1 and LM2904BA-Q1)
- Common-mode input voltage range includes ground, enabling direct sensing near ground
- Low input offset voltage of 2 mV at 25°C (LM2904BA-Q1, maximum)
- Low input offset voltage of 3 mV at 25°C (LM2904B-Q1, maximum)
- Internal RF and EMI filter (LM2904B-Q1 and LM2904BA-Q1)
- **Functional Safety-Capable**
 - [Documentation available to aid functional safety system design](#)

2 Applications

- [Automotive lighting](#)
- [Body electronics](#)
- [Automotive head unit](#)
- [Telematics control unit](#)
- [Emergency call \(eCall\)](#)
- [Passive safety: brake system](#)
- Electric vehicle / hybrid electric:
 - [Inverter and motor control](#)
 - [On-board \(OBC\) and wireless charger](#)
 - [Battery management system \(BMS\)](#)

3 Description

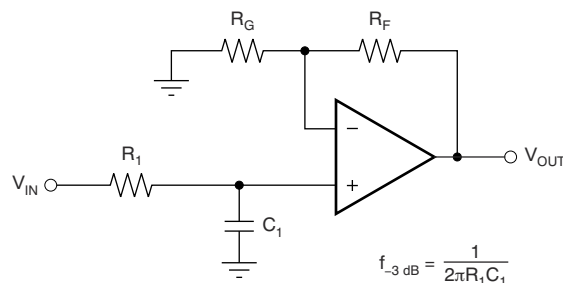
The LM2904-Q1, LM2904B-Q1, and LM2904BA-Q1 are industry-standard operational amplifiers that have been qualified for automotive use in accordance to the AEC-Q100 specifications. The LM2904B-Q1 and LM2904BA-Q1 are the next-generation versions of the LM2904-Q1, which include two high-voltage (36 V) operational amplifiers (op amps). The LM2904B-Q1 and LM2904BA-Q1 provide outstanding value for cost-sensitive applications, with features including low offset (3 mV and 2 mV maximum, respectively), common-mode input range to ground, and high differential input voltage capability.

The LM2904B-Q1 and LM2904BA-Q1 simplify circuit design with enhanced features such as unity-gain stability, lower offset voltage of 0.3 mV (typical), and lower quiescent current of 300 µA (typical). High ESD (2 kV, HBM) and integrated EMI and RF filters enable the LM2904B-Q1 and LM2904BA-Q1 devices to be used in the most rugged, environmentally challenging applications for the automotive marketplace.

Device Information

PART NUMBER ⁽¹⁾	PACKAGE	BODY SIZE (NOM)
LM2904B-Q1	SOIC (8)	4.90 mm × 3.90 mm
	TSSOP (8)	3.00 mm × 4.40 mm
	VSSOP (8)	3.00 mm × 3.00 mm
LM2904BA-Q1	SOIC (8)	4.90 mm × 3.90 mm
	TSSOP (8)	3.00 mm × 4.40 mm
	VSSOP (8)	3.00 mm × 3.00 mm
LM2904-Q1	SOIC (8)	4.90 mm × 3.90 mm
	TSSOP (8)	3.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1 C_1}\right)$$

Single-Pole, Low-Pass Filter



Table of Contents

1 Features	1	9.3 Feature Description.....	20
2 Applications	1	9.4 Device Functional Modes.....	20
3 Description	1	10 Application and Implementation	21
4 Revision History	2	10.1 Application Information.....	21
5 Device Comparison Table	4	10.2 Typical Application.....	21
6 Pin Configuration and Functions	5	11 Power Supply Recommendations	23
7 Specifications	6	12 Layout	24
7.1 Absolute Maximum Ratings.....	6	12.1 Layout Guidelines.....	24
7.2 ESD Ratings.....	6	12.2 Layout Examples.....	24
7.3 Recommended Operating Conditions.....	7	13 Device and Documentation Support	25
7.4 Thermal Information.....	7	13.1 Documentation Support.....	25
7.5 Electrical Characteristics: LM2904B-Q1 and LM2904BA-Q1.....	8	13.2 Related Links.....	25
7.6 Electrical Characteristics: LM2904-Q1, LM2904AV-Q1, LM2904V-Q1.....	10	13.3 Receiving Notification of Documentation Updates.....	25
7.7 Typical Characteristics.....	11	13.4 Support Resources.....	25
8 Parameter Measurement Information	18	13.5 Trademarks.....	25
9 Detailed Description	19	13.6 Electrostatic Discharge Caution.....	25
9.1 Overview.....	19	13.7 Glossary.....	25
9.2 Functional Block Diagram.....	19	14 Mechanical, Packaging, and Orderable Information	26

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision J (February 2021) to Revision K (April 2022) Page

• Added LM2904BA-Q1 to data sheet.....	1
• Increased ESD (CDM) rating for LM2904B-Q1 and LM2904BA-Q1 from ± 750 V to ± 1500 V.....	6

Changes from Revision I (June 2020) to Revision J (February 2021) Page

• Updated the numbering format for tables, figures, and cross-references throughout the document	1
• Added Functional Safety-Capable feature and link to supporting document in <i>Features</i> section	1
• Deleted preview tag on VSSOP (8) package throughout the data sheet.....	1
• Deleted SOT-23 (8) package information throughout the data sheet.....	1
• Deleted preview tag from VSSOP package in <i>Pin Configuration and Functions</i> section.....	5
• Deleted DDF (SOT23-8) package in <i>Pin Configuration and Functions</i> section.....	5
• Updated VSSOP package thermal information in <i>Thermal Information</i> section.....	7

Changes from Revision H (December 2019) to Revision I (June 2020) Page

• Added applications link in <i>Application</i> section.....	1
• Deleted preview tag on TSSOP (8) package in <i>Device Information</i> table	1
• Added information on VSSOP-8 package to <i>Device Information</i> table.....	1
• Added information on VSSOP-8 package to the <i>Device Comparison Table</i> section.....	4
• Deleted preview tag on TSSOP-8 package in the <i>Device Comparison Table</i> section.....	4
• Deleted preview tag from TSSOP package in <i>Pin Configuration and Functions</i> section.....	5
• Added VSSOP package information in <i>Pin Configuration and Functions</i> section.....	5
• Added VSSOP package to <i>Thermal Information</i> table	7
• Changed section title from <i>Community Resources</i> to <i>Support Resources</i> in the <i>Device and Documentation Support</i> section.....	25

Changes from Revision G (February 2019) to Revision H (December 2019) Page

• Added information on SOT23-8 package to <i>Device Information</i> table.....	1
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• Added information on SOT23-8 package to the <i>Device Comparison Table</i>	4
• Added the <i>Typical Characteristics</i> section for the LM2904B-Q1 device.....	11
• Added test circuit for THD+N and small-signal step response, $G = -1$ in the <i>Parameter Measurement Information</i> section.....	18
• Changed specific voltages to a <i>Recommended Operating Conditions</i> reference.....	19
• Changed the functional block diagram for LM2904B-Q1 in the <i>Detailed Description</i> section.....	19

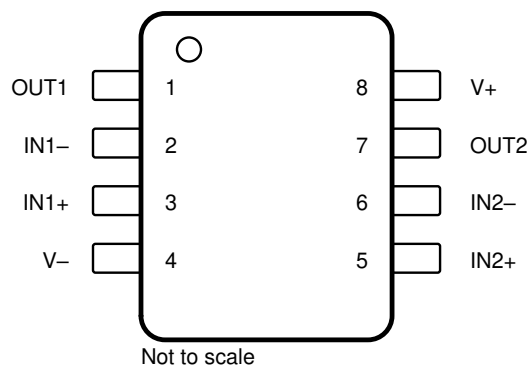
Changes from Revision F (April 2008) to Revision G (February 2019)	Page
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• Added <i>Applications</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1
• Added new device to data sheet.....	1
• Added AEC-Q100 qualification statement.....	1

5 Device Comparison Table

PART NUMBER	SUPPLY VOLTAGE	AMBIENT TEMPERATURE RANGE	V _{OS} (MAXIMUM AT 25°C)	I _Q / CH (TYPICAL AT 25°C)	INTEGRATED EMI FILTER	PACKAGE
LM2904B-Q1	3 V to 36 V	–40°C to 125°C	3 mV	300 µA	Yes	D, DGK, PW
LM2904BA-Q1	3 V to 36 V	–40°C to 125°C	2 mV	300 µA	Yes	D, DGK, PW
LM2904-Q1	3 V to 26 V	–40°C to 125°C	7 mV	350 µA	No	D, PW
LM2904V-Q1	3 V to 32 V	–40°C to 125°C	7 mV	350 µA	No	D, PW
LM2904AV-Q1	3 V to 32 V	–40°C to 125°C	2 mV	350 µA	No	D, PW

6 Pin Configuration and Functions



**Figure 6-1. D, DGK, and PW Package
8-Pin SOIC, VSSOP, and TSSOP
Top View**

Table 6-1. Pin Functions

PIN ⁽¹⁾		I/O	DESCRIPTION
NAME	NO.		
IN1–	2	I	Negative input
IN1+	3	I	Positive input
IN2–	6	I	Negative input
IN2+	5	I	Positive input
OUT1	1	O	Output
OUT2	7	O	Output
V–	4	—	Negative (lowest) supply or ground (for single-supply operation)
V+	8	—	Positive (highest) supply

(1) For a listing of which devices are available in what packages, see [Section 5](#).

7 Specifications

7.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
Supply voltage, $V_S = ([V+] - [V-])$		LM2904B-Q1, LM2904BA-Q1		40	V
		LM2904V-Q1, LM2904AV-Q1		32	
		LM2904-Q1		26	
Differential input voltage, V_{ID} ⁽²⁾		LM2904B-Q1, LM2904BA-Q1, LM2904V-Q1, LM2904AV-Q1	–32	32	V
		LM2904-Q1	–26	26	
Input voltage, V_I	Either input	LM2904B-Q1, LM2904BA-Q1	–0.3	40	V
		LM2904V-Q1, LM2904AV-Q1	–0.3	32	
		LM2904-Q1	–0.3	26	
Duration of output short circuit (one amplifier) to V_- at (or below) $T_A = 25^\circ\text{C}$, $V_S \leq 15\text{ V}$ ⁽³⁾			Unlimited		s
Operating ambient temperature, T_A			–40	125	$^\circ\text{C}$
Operating virtual-junction temperature, T_J				150	$^\circ\text{C}$
Storage temperature, T_{stg}			–65	150	$^\circ\text{C}$

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Differential voltages are at $IN+$, with respect to $IN-$.

(3) Short circuits from outputs to the supply pins can cause excessive heating and eventual destruction.

7.2 ESD Ratings

		VALUE	UNIT	
LM2904B-Q1 and LM2904BA-Q1				
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
		Charged-device model (CDM), per AEC Q100-011	±1500	
LM2904-Q1, LM2904AV-Q1, AND LM2904V-Q1				
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±1000	V
		Charged-device model (CDM), per AEC Q100-011	±500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

		MIN	MAX	UNIT	
V _S	Supply voltage, V _S = ([V+] – [V–])	LM2904B-Q1, LM2904BA-Q1	3	36	V
		LM2904AV-Q1, LM2904V-Q1	3	30	
		LM2904-Q1	3	26	
V _{CM}	Common-mode voltage	V–	(V+) – 2		V
T _A	Operating ambient temperature	–40	125		°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM2904-Q1, LM2904AV-Q1, LM2904B-Q1, LM2904BA-Q1, LM2904V-Q1 ⁽²⁾			UNIT
		D (SOIC)	DGK (VSSOP)	PW (TSSOP)	
		8 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	124.7	186.1	171.7	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	66.9	77.1	68.8	°C/W
R _{θJB}	Junction-to-board thermal resistance	67.9	107.7	99.2	°C/W
ψ _{JT}	Junction-to-top characterization parameter	19.2	17.2	11.5	°C/W
ψ _{JB}	Junction-to-board characterization parameter	67.2	106.1	97.9	°C/W

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

(2) For a listing of which devices are available in what packages, see [Section 5](#).

7.5 Electrical Characteristics: LM2904B-Q1 and LM2904BA-Q1

$V_S = (V+) - (V-) = 5\text{ V} - 36\text{ V} (\pm 2.5\text{ V} - \pm 18\text{ V})$, $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE								
V _{OS}	Input offset voltage	LM2904B-Q1				±0.3	±3.0	mV
			T _A = −40°C to +125°C			±4		
		LM2904BA-Q1				±2.0		mV
			T _A = −40°C to +125°C			±3.0		mV
dV _{OS} /dT	Input offset voltage drift		T _A = −40°C to +125°C ⁽¹⁾		±3.5	12	μV/°C	
PSRR	Power supply rejection ratio				±2	15	μV/V	
	Channel separation, dc	f = 1 kHz to 20 kHz			±1		μV/V	
INPUT VOLTAGE RANGE								
V _{CM}	Common-mode voltage range	V _S = 3 V to 36 V		(V−)	(V+) − 1.5	V		
		V _S = 5 V to 36 V	T _A = −40°C to +125°C	(V−)	(V+) − 2			
CMRR	Common-mode rejection ratio	(V−) ≤ V _{CM} ≤ (V+) − 1.5 V	V _S = 3 V to 36 V		20	100	μV/V	
		(V−) ≤ V _{CM} ≤ (V+) − 2.0 V	V _S = 5 V to 36 V	T _A = −40°C to +125°C	25	316		
INPUT BIAS CURRENT								
I _B	Input bias current				±10	±35	nA	
			T _A = −40°C to +125°C ⁽¹⁾			±50		
I _{OS}	Input offset current				0.5	4	nA	
			T _A = −40°C to +125°C ⁽¹⁾			5		
dI _{OS} /dT	Input offset current drift		T _A = −40°C to +125°C		10		pA/°C	
NOISE								
E _n	Input voltage noise	f = 0.1 to 10 Hz			3		μV _{PP}	
e _n	Input voltage noise density	f = 1 kHz			40		nV/√Hz	
INPUT IMPEDANCE								
Z _{ID}	Differential				10 0.1		MΩ pF	
Z _{IC}	Common-mode				4 1.5		GΩ pF	
OPEN-LOOP GAIN								
A _{OL}	Open-loop voltage gain	V _S = 15 V; V _O = 1 V to 11 V; R _L ≥ 10 kΩ, connected to (V−)		70	140	V/mV		
			T _A = −40°C to +125°C	35				
FREQUENCY RESPONSE								
GBW	Gain bandwidth product				1.2		MHz	
SR	Slew rate	G = + 1			0.5		V/μs	
Θ _m	Phase margin	G = + 1, R _L = 10 kΩ, C _L = 20 pF			56		°	
t _{OR}	Overload recovery time	V _{IN} × gain > V _S			10		μs	
t _s	Settling time	To 0.1%, V _S = 5 V, 2-V Step , G = +1, C _L = 100 pF			4		μs	
THD+N	Total harmonic distortion + noise	G = + 1, f = 1 kHz, V _O = 3.53 V _{RMS} , V _S = 36 V, R _L = 100k, I _{OUT} ≤ ±50 μA, BW = 80 kHz			0.001%			
OUTPUT								
V _O	Voltage output swing from rail	Positive rail (V+)		I _{OUT} = 50 μA	1.35	1.42	V	
				I _{OUT} = 1 mA	1.4	1.48		
				I _{OUT} = 5 mA ⁽¹⁾	1.5	1.61		
		Negative rail (V−)		I _{OUT} = 50 μA	100	150	mV	
				I _{OUT} = 1 mA	0.75	1	V	
			V _S = 5 V, RL ≤ 10 kΩ connected to (V−)	T _A = −40°C to +125°C	5	20	mV	
I _O	Output current	V _S = 15 V; V _O = V−; V _{ID} = 1 V	Source ⁽¹⁾		-20	-30	mA	
				T _A = −40°C to +125°C	-10			
		V _S = 15 V; V _O = V+; V _{ID} = -1 V	Sink ⁽¹⁾		10	20		
				T _A = −40°C to +125°C	5			
	V _{ID} = -1 V; V _O = (V−) + 200 mV			60	100	μA		
I _{SC}	Short-circuit current	V _S = 20 V, (V+) = 10 V, (V−) = -10 V, V _O = 0 V			±40	±60	mA	
C _{LOAD}	Capacitive load drive				100		pF	
R _O	Open-loop output resistance	f = 1 MHz, I _O = 0 A			300		Ω	
POWER SUPPLY								

7.5 Electrical Characteristics: LM2904B-Q1 and LM2904BA-Q1 (continued)

$V_S = (V_+) - (V_-) = 5\text{ V} - 36\text{ V} (\pm 2.5\text{ V} - \pm 18\text{ V})$, $T_A = 25^\circ\text{C}$, $V_{CM} = V_{OUT} = V_S / 2$, $R_L = 10\text{k}$ connected to $V_S / 2$
(unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_Q	Quiescent current per amplifier	$V_S = 5\text{ V}; I_O = 0\text{ A}$	$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		300	460	μA
		$V_S = 36\text{ V}; I_O = 0\text{ A}$				800	

(1) Specified by characterization only.

7.6 Electrical Characteristics: LM2904-Q1, LM2904AV-Q1, LM2904V-Q1

For $V_S = (V+) - (V-) = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to V_- (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT		
OFFSET VOLTAGE									
V _{OS}	Input offset voltage	V _S = 5 V to maximum; V _{C M} = 0 V; V _O = 1.4 V	LM2904-Q1, LM2904V-A1		±3	±7	mV		
				T _A = −40°C to 125°C		±10			
			LM2904AV-Q1		±1	±2			
				T _A = −40°C to 125°C		±4			
dV _{OS} /dT	Input offset voltage drift		T _A = −40°C to 125°C		±7		μV/°C		
PSRR	Input offset voltage vs power supply (ΔV _{IO} /ΔV _S)	V _S = 5 V to 30 V		65	100		dB		
V _{O1} / V _{O2}	Channel separation	f = 1 kHz to 20 kHz			120		dB		
INPUT VOLTAGE RANGE									
V _{CM}	Common-mode voltage range	V _S = 5 V to maximum		(V−)	(V+) − 1.5		V		
			T _A = −40°C to 125°C	(V−)	(V+) − 2				
CMRR	Common-mode rejection ratio	V _S = 5 V to maximum; V _{CM} = 0 V		65	80		dB		
INPUT BIAS CURRENT									
I _B	Input bias current	V _O = (V−) + 1.4 V			−20	−250	nA		
				T _A = −40°C to 125°C		−500			
I _{OS}	Input offset current	V _O = (V−) + 1.4 V	LM2904-Q1		2	50	nA		
				T _A = −40°C to 125°C		300			
			LM2904AV-Q1, LM2904V-Q1		2	50			
				T _A = −40°C to 125°C		150			
dI _{OS} /dT	Input offset current drift		T _A = −40°C to 125°C		10		pA/°C		
NOISE									
e _n	Input voltage noise density	f = 1 kHz			40		nV/√ Hz		
OPEN-LOOP GAIN									
A _{OL}	Open-loop voltage gain	V _S = 15 V; V _O = (V−) + 1 V to (V−) + 11 V; R _L ≥ 2 kΩ, connected to (V−)		25	100		V/mV		
				T _A = −40°C to 125°C	15				
FREQUENCY RESPONSE									
GBW	Gain bandwidth product				0.7		MHz		
SR	Slew rate	G = +1			0.3		V/μs		
OUTPUT									
V _O	Voltage output swing from rail	Positive rail	R _L ≥ 10 kΩ	T _A = −40°C to 125°C	V _S − 1.5		V		
					4				
			LM2904-Q1		V _S = maximum; R _L = 2 kΩ	3		2	
					V _S = maximum; R _L ≥ 10 kΩ	6			
		LM2904AV-Q1, LM2904V-Q1	V _S = maximum; R _L = 2 kΩ		5		4		
			V _S = maximum; R _L ≥ 10 kΩ		5		20		
I _O	Output current	Negative rail		T _A = −40°C to 125°C	5		mV		
		V _S = 5 V; R _L ≤ 10 kΩ							
		V _S = 15 V; V _O = V−; V _{ID} = 1 V	Source	T _A = −40°C to 125°C	−20		−30	mA	
					−10				
			V _S = 15 V; V _O = V+; V _{ID} = −1 V		Sink	10			20
V _{ID} = −1 V; V _O = (V−) + 200 mV	LM2904-Q1	LM2904AV-Q1, LM2904V-Q1	30			μA			
			12		40				
I _{SC}	Short-circuit current	V _S = 10 V; V _O = V _S / 2			±40	±60	mA		
POWER SUPPLY									
I _Q	Quiescent current per amplifier	V _O = V _S / 2; I _O = 0 A		T _A = −40°C to 125°C	350	600	μA		
		V _S = maximum; V _O = maximum / 2; I _O = 0 A			500	1000			

(1) All characteristics are measured with zero common-mode input voltage, unless otherwise specified. Maximum V_S for testing purposes is 26 V for LM2904-Q1 and 32 V for LM2904AV-Q1/LM2904V-Q1.

7.7 Typical Characteristics

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).

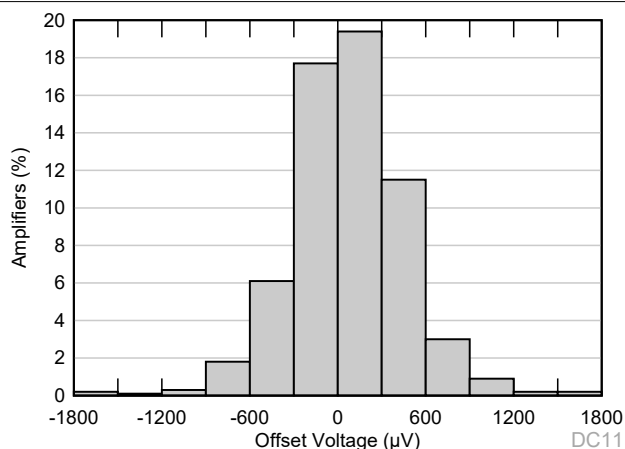


Figure 7-1. Offset Voltage Production Distribution

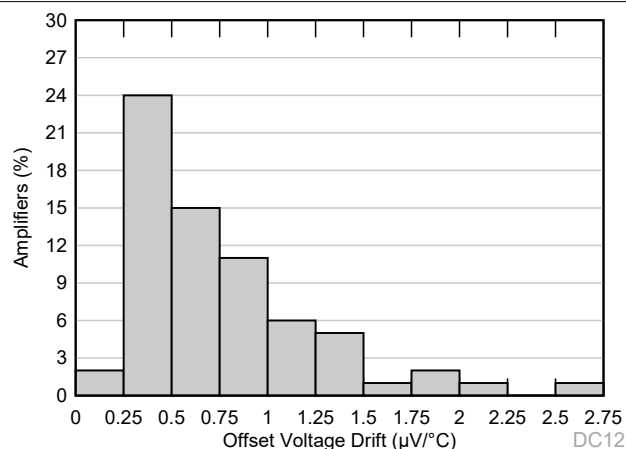


Figure 7-2. Offset Voltage Drift Distribution

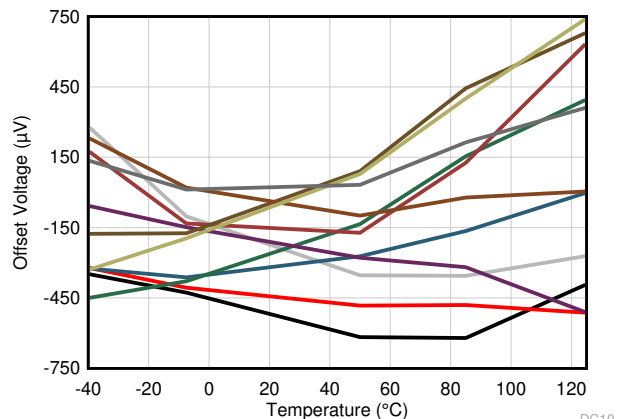


Figure 7-3. Offset Voltage vs Temperature

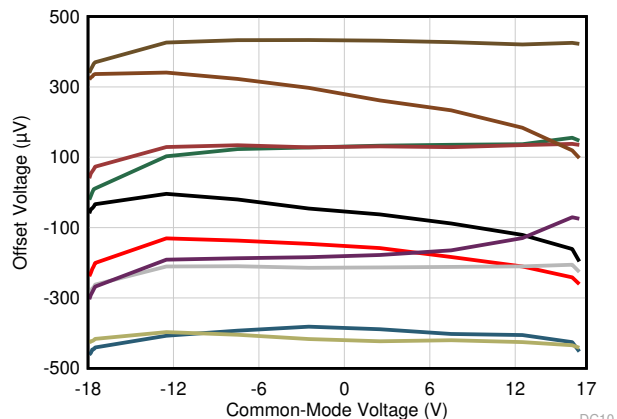


Figure 7-4. Offset Voltage vs Common-Mode Voltage

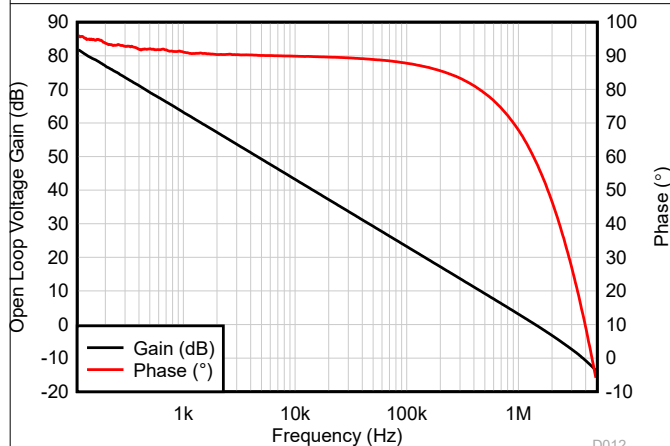


Figure 7-5. Open-Loop Gain and Phase vs Frequency

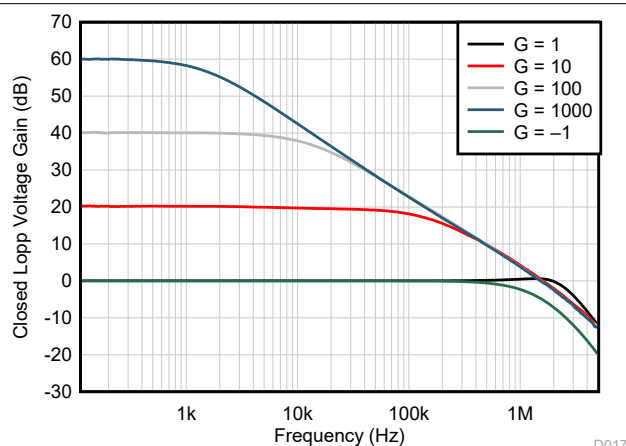


Figure 7-6. Closed-Loop Gain vs Frequency

7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).

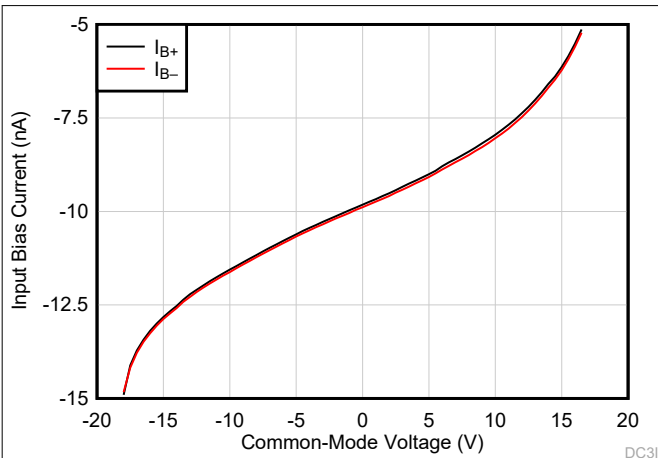


Figure 7-7. Input Bias Current vs Common-Mode Voltage

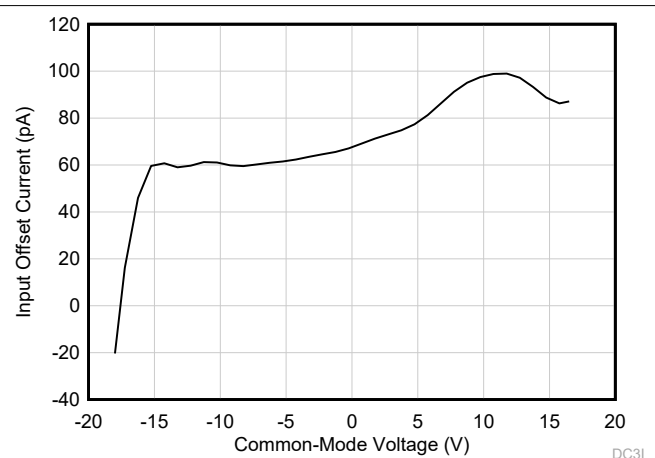


Figure 7-8. Input Offset Current vs Common-Mode Voltage

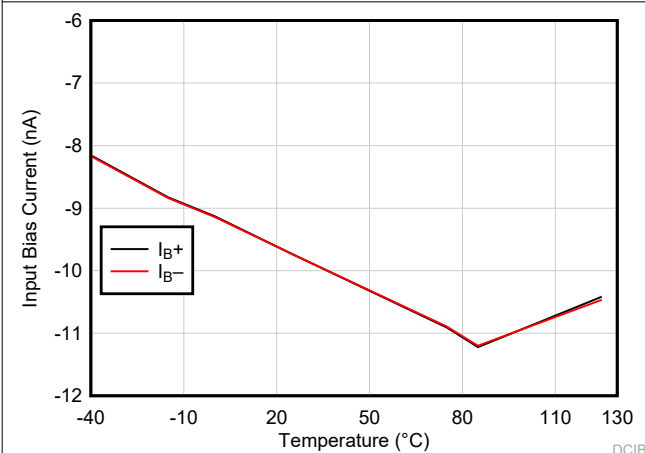


Figure 7-9. Input Bias Current vs Temperature

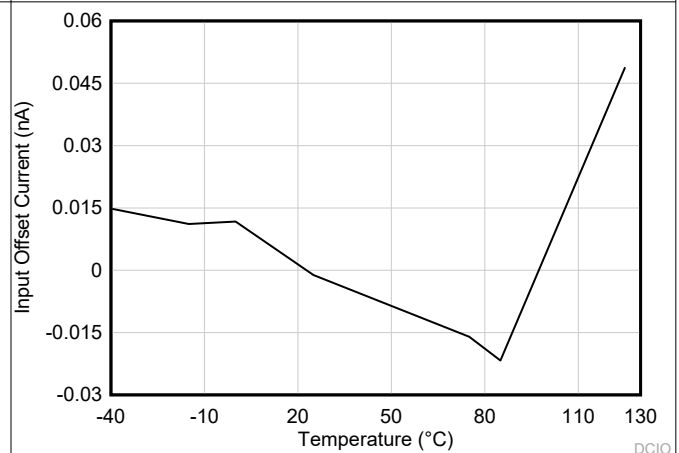


Figure 7-10. Input Offset Current vs Temperature

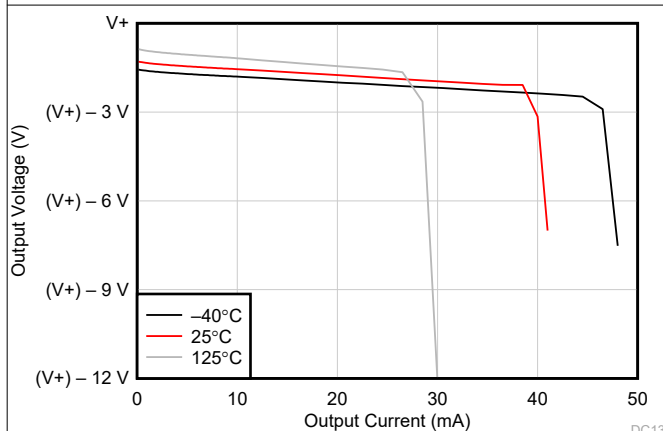


Figure 7-11. Output Voltage Swing vs Output Current (Sourcing)

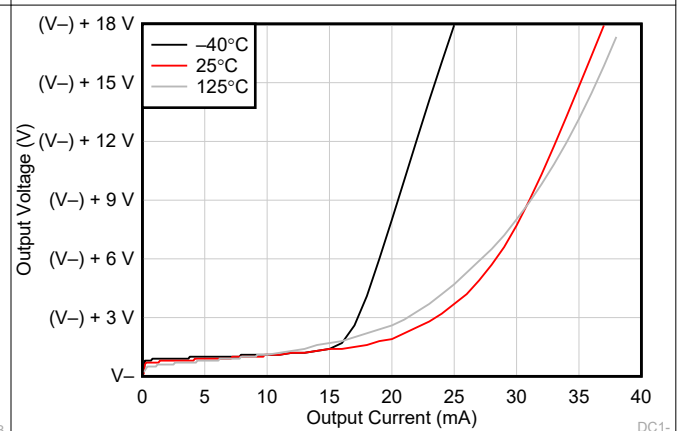


Figure 7-12. Output Voltage Swing vs Output Current (Sinking)

7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).

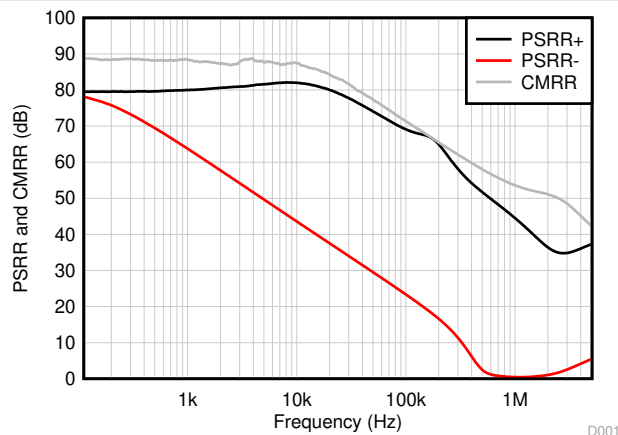


Figure 7-13. CMRR and PSRR vs Frequency

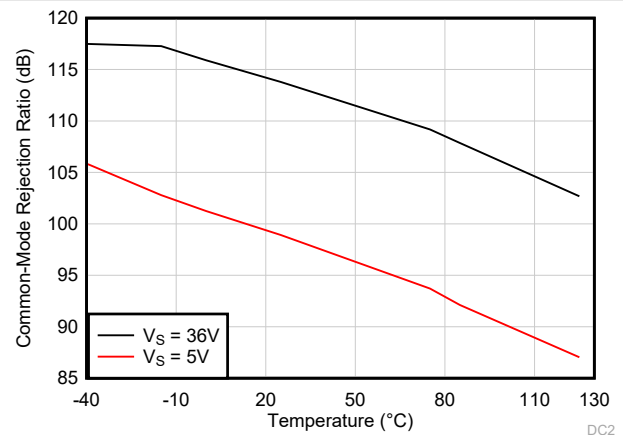


Figure 7-14. Common-Mode Rejection Ratio vs Temperature (dB)

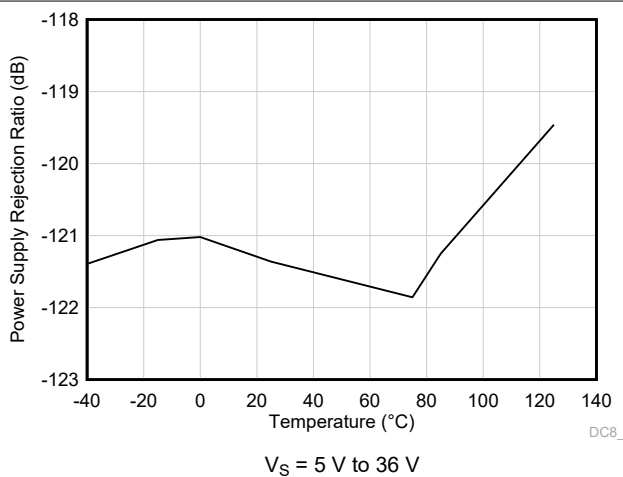


Figure 7-15. Power Supply Rejection Ratio vs Temperature (dB)

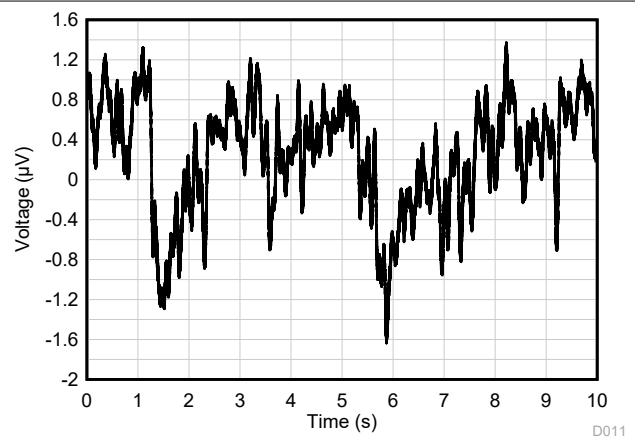


Figure 7-16. 0.1-Hz to 10-Hz Noise

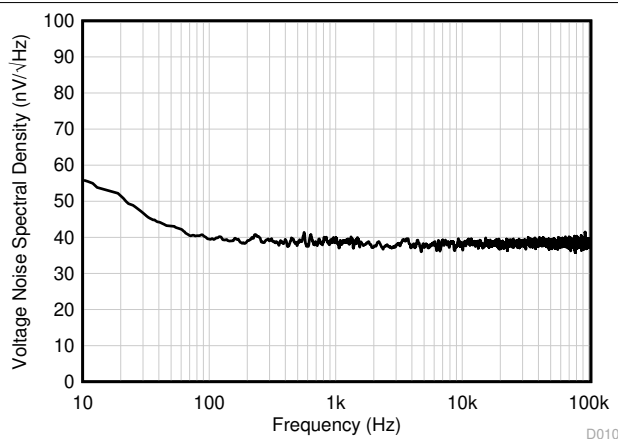


Figure 7-17. Input Voltage Noise Spectral Density vs Frequency

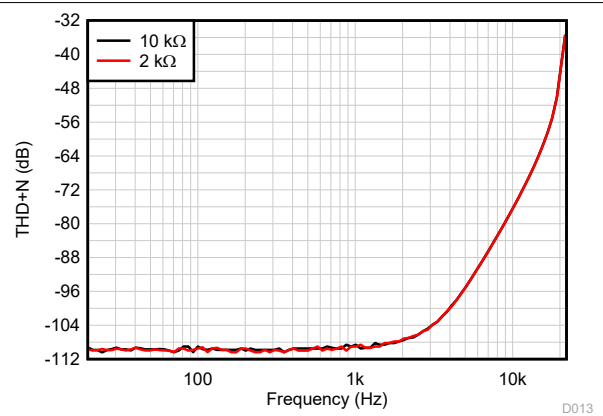
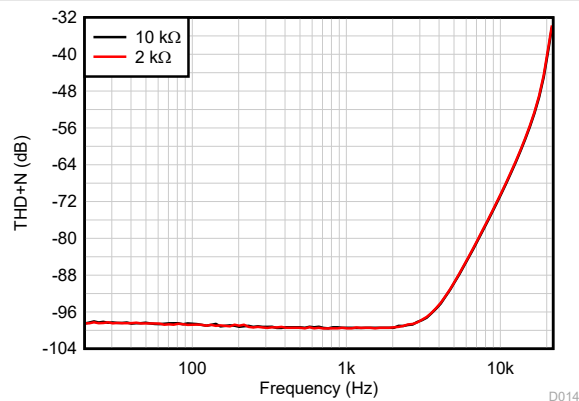


Figure 7-18. THD+N Ratio vs Frequency, $G = 1$
 $G = 1$, $f = 1\text{ kHz}$, $BW = 80\text{ kHz}$,
 $V_{OUT} = 10\text{ V}_{PP}$, R_L connected to V_-

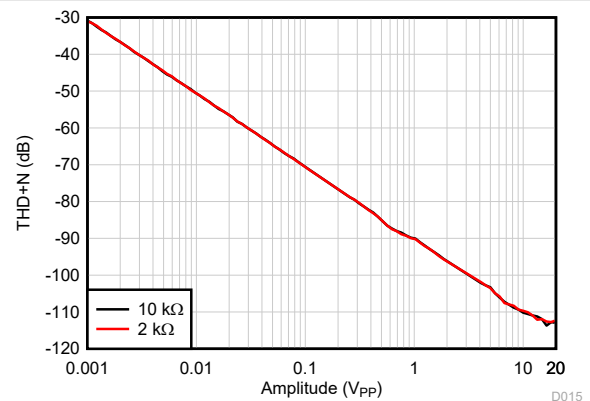
7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).



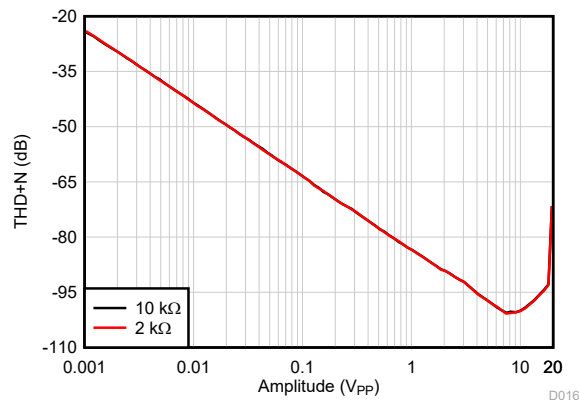
$G = -1$, $f = 1\text{ kHz}$, $BW = 80\text{ kHz}$,
 $V_{OUT} = 10\text{ V}_{PP}$, R_L connected to V_-
See Figure 8-3

Figure 7-19. THD+N Ratio vs Frequency, $G = -1$



$G = 1$, $f = 1\text{ kHz}$, $BW = 80\text{ kHz}$,
 R_L connected to V_-

Figure 7-20. THD+N vs Output Amplitude, $G = 1$



$G = -1$, $f = 1\text{ kHz}$, $BW = 80\text{ kHz}$,
 R_L connected to V_-
See Figure 8-3

Figure 7-21. THD+N vs Output Amplitude, $G = -1$

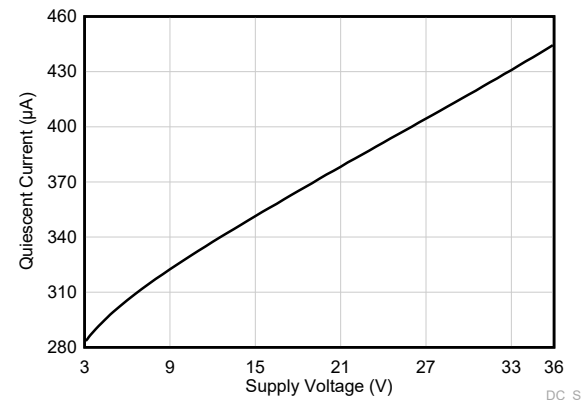


Figure 7-22. Quiescent Current vs Supply Voltage

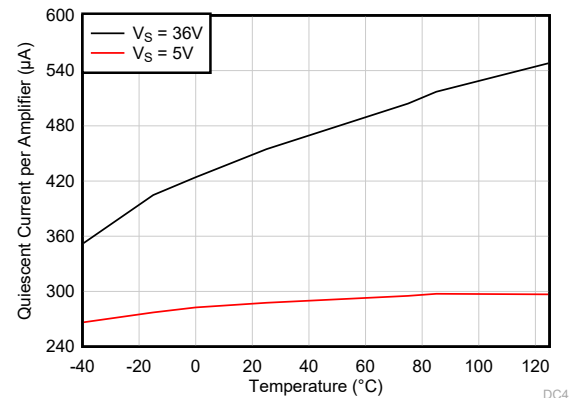


Figure 7-23. Quiescent Current vs Temperature

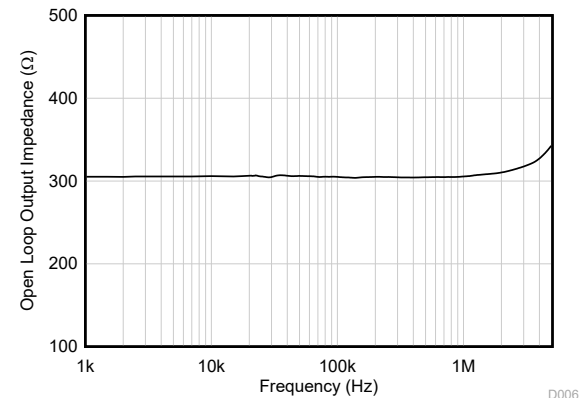


Figure 7-24. Open-Loop Output Impedance vs Frequency

7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).

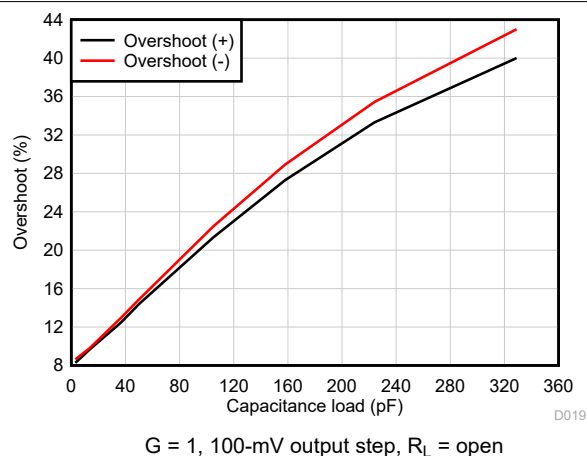


Figure 7-25. Small-Signal Overshoot vs Capacitive Load

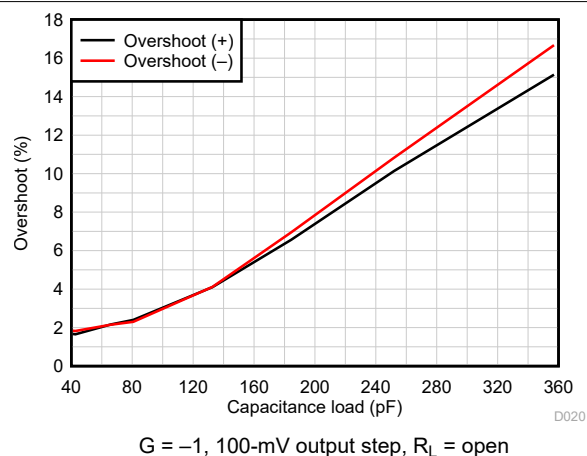


Figure 7-26. Small-Signal Overshoot vs Capacitive Load

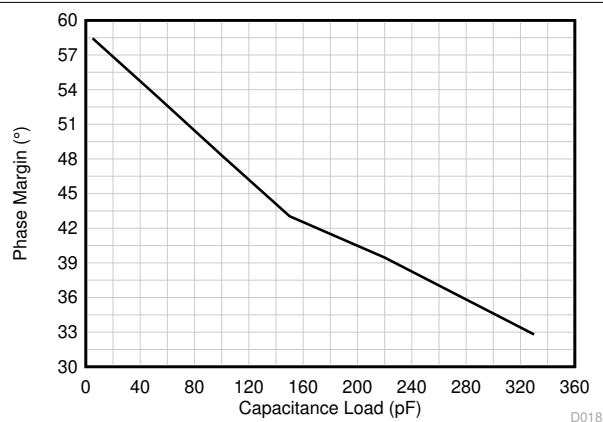


Figure 7-27. Phase Margin vs Capacitive Load

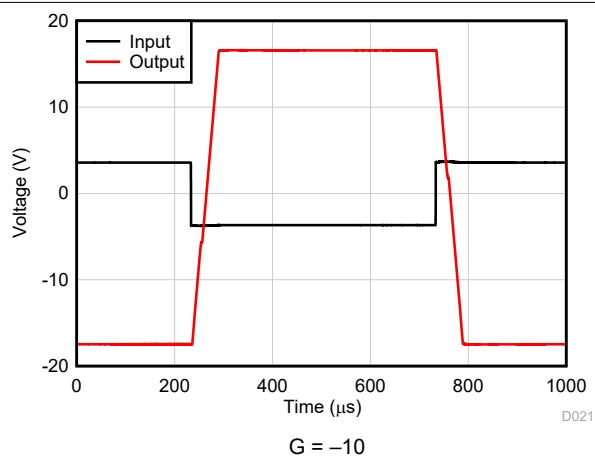


Figure 7-28. Overload Recovery

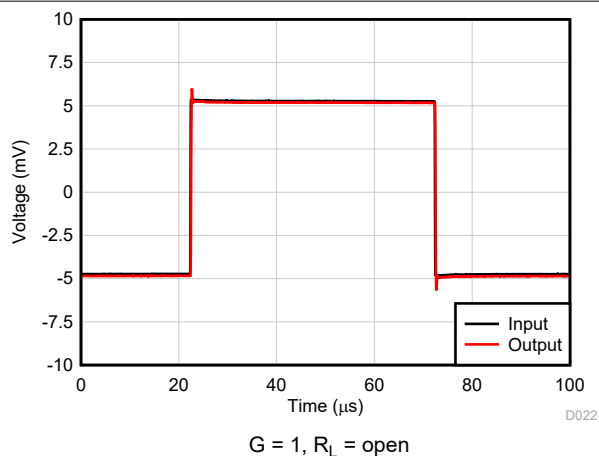


Figure 7-29. Small-Signal Step Response, G = 1

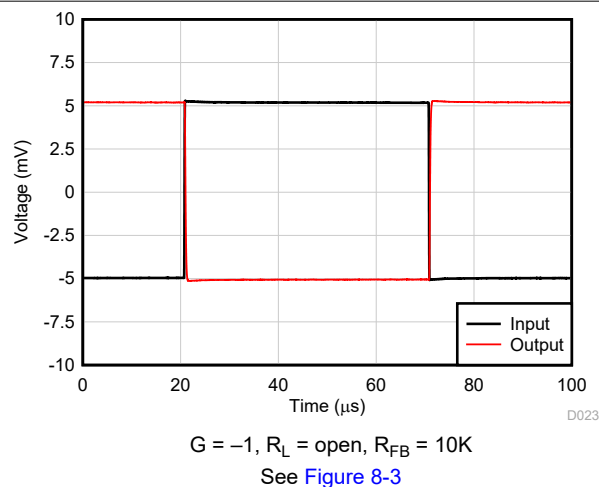
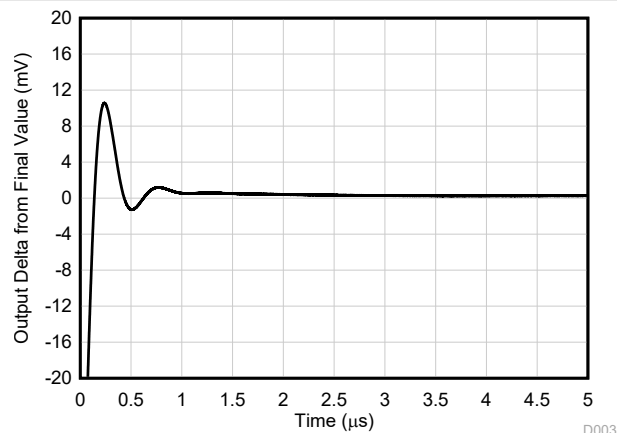


Figure 7-30. Small-Signal Step Response, G = -1

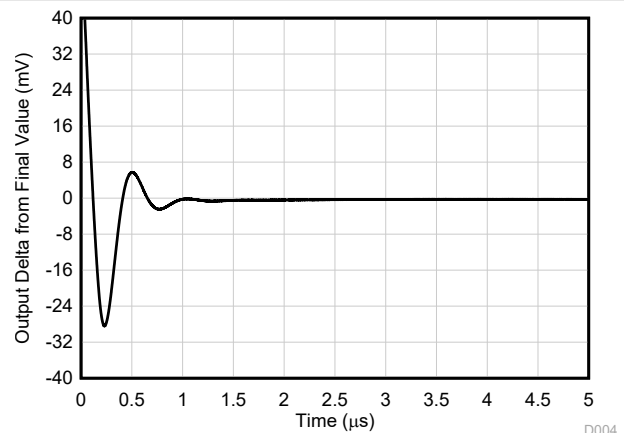
7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).



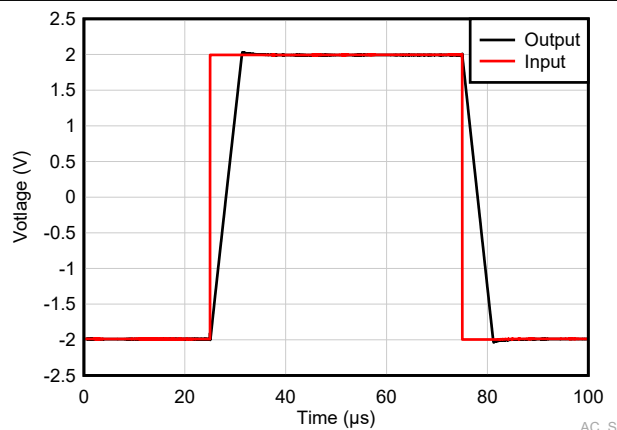
$G = 1$, $R_L = \text{open}$

Figure 7-31. Large-Signal Step Response (Rising)



$G = 1$, $R_L = \text{open}$

Figure 7-32. Large-Signal Step Response (Falling)



$G = 1$, $R_L = \text{open}$

Figure 7-33. Large-Signal Step Response

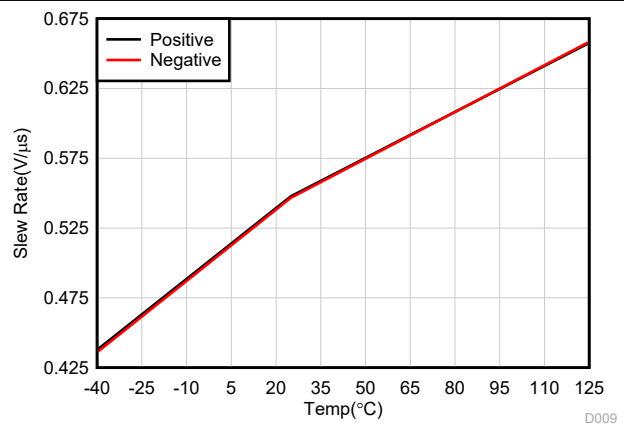


Figure 7-34. Slew Rate vs Temperature

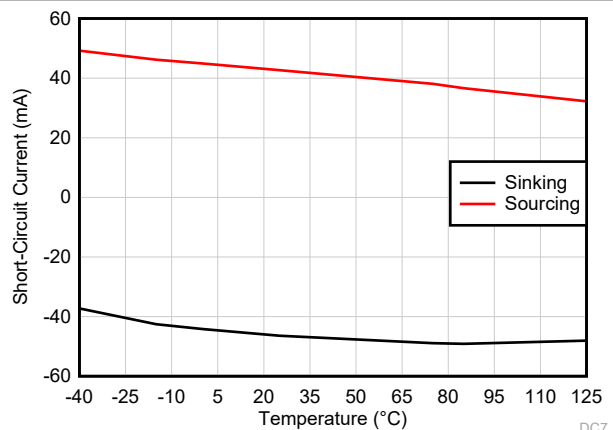
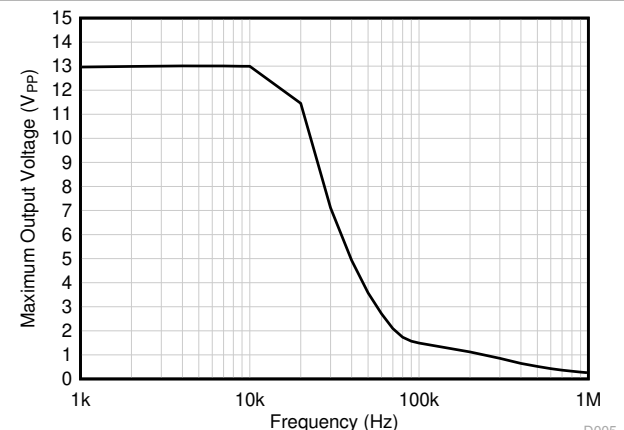


Figure 7-35. Short-Circuit Current vs Temperature



$V_S = 15\text{ V}$

Figure 7-36. Maximum Output Voltage vs Frequency

7.7 Typical Characteristics (continued)

Typical characteristics section is applicable for LM2904B-Q1 and LM2904BA-Q1. The typical characteristics data section was taken with $T_A = 25^\circ\text{C}$, $V_S = 36\text{ V}$ ($\pm 18\text{ V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted).

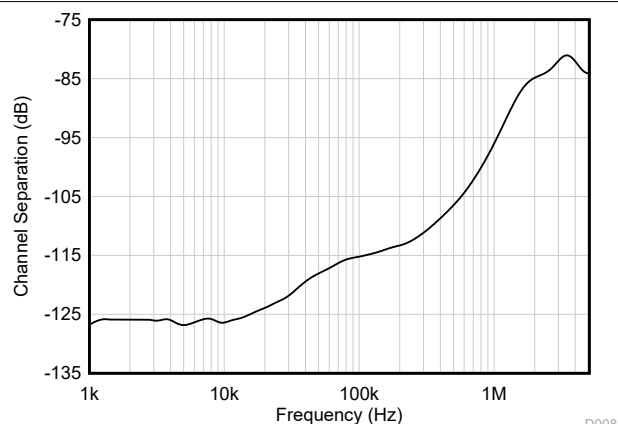


Figure 7-37. Channel Separation vs Frequency

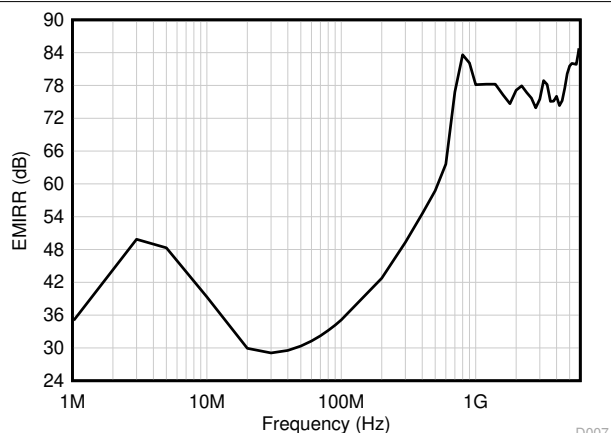


Figure 7-38. EMIRR (Electromagnetic Interference Rejection Ratio) vs Frequency

8 Parameter Measurement Information

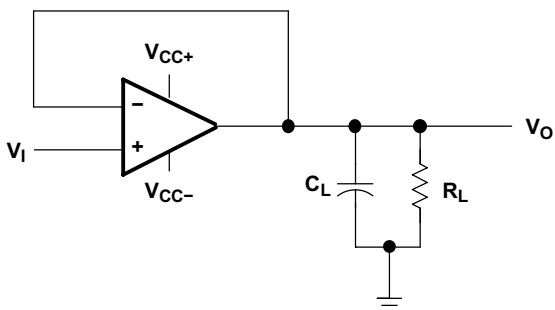


Figure 8-1. Unity-Gain Amplifier

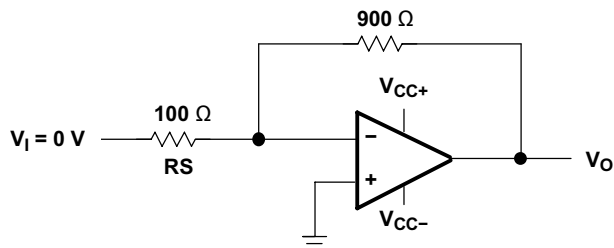


Figure 8-2. Noise-Test Circuit

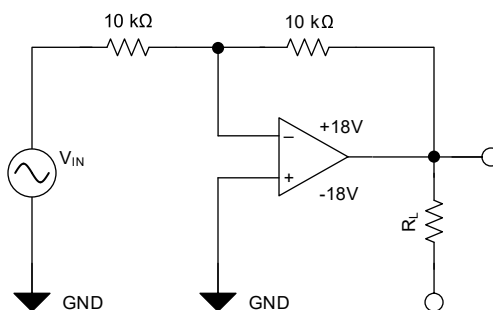


Figure 8-3. Test Circuit, $G = -1$, for THD+N and Small-Signal Step Response

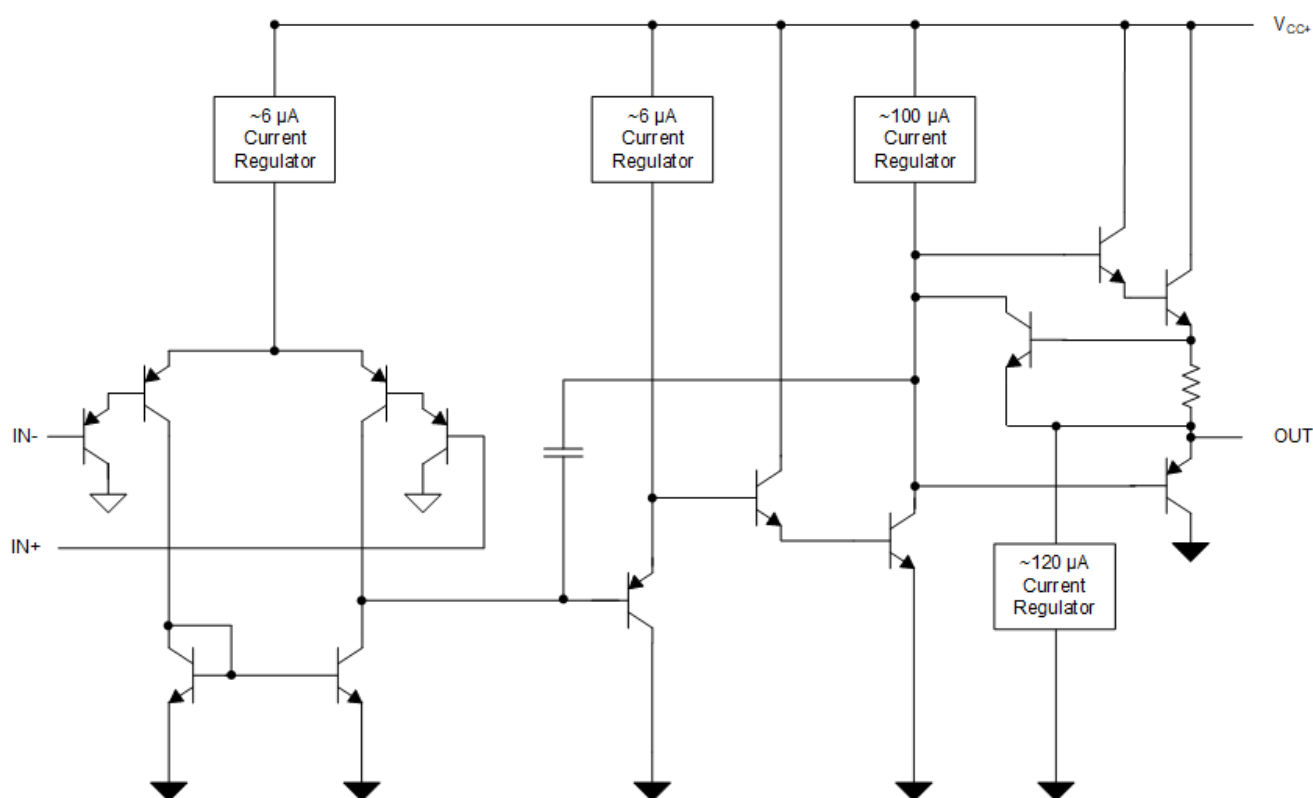
9 Detailed Description

9.1 Overview

The LM2904-Q1, LM2904B-Q1, and LM2904BA-Q1 devices consist of two independent, high-gain frequency-compensated operational amplifiers designed to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is within the supply voltage range specified in [Section 7.3](#), and V_S is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, DC amplification blocks, and all the conventional operational amplifier circuits that now can be implemented more easily in single-supply-voltage systems. For example, these devices can be operated directly from the standard 5-V supply used in digital systems and easily can provide the required interface electronics without additional ± 5 -V supplies.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Unity-Gain Bandwidth

The unity-gain bandwidth is the frequency up to which an amplifier with a unity gain may be operated without greatly distorting the signal. These devices have a 1.2-MHz unity-gain bandwidth (LM2904B-Q1 and LM2904BA-Q1).

9.3.2 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. These devices have a 0.5-V/ μ s slew rate (LM2904B-Q1 and LM2904BA-Q1).

9.3.3 Input Common Mode Range

The valid common mode range is from device ground to $V_S - 1.5\text{ V}$ ($V_S - 2\text{ V}$ across temperature). Inputs may exceed V_S up to the maximum V_S without device damage. At least one input must be in the valid input common-mode range for the output to be the correct phase. If both inputs exceed the valid range, then the output phase is undefined. If either input more than 0.3 V below V_- then input current should be limited to 1 mA and the output phase is undefined.

9.4 Device Functional Modes

The LM2904-Q1, LM2904B-Q1, and LM2904BA-Q1 devices are powered on when the supply is connected. This device can be operated as a single-supply operational amplifier or dual-supply amplifier, depending on the application.

10 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The LM2904-Q1, LM2904B-Q1, LM2904BA-Q1 operational amplifiers are useful in a wide range of signal conditioning applications. Inputs can be powered before V_S for flexibility in multiple supply circuits. For full application design guidelines related to this family of devices, please refer to the application report [Application design guidelines for LM324/LM358 devices](#).

10.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier. This amplifier takes a positive voltage on the input, and makes it a negative voltage of the same magnitude. In the same manner, it also makes negative voltages positive.

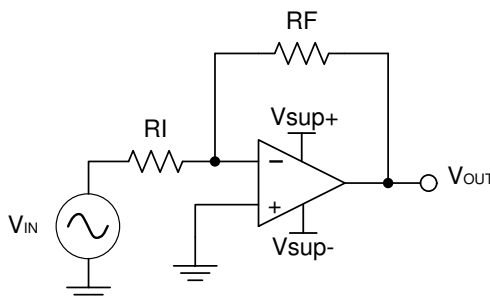


Figure 10-1. Application Schematic

10.2.1 Design Requirements

The supply voltage must be chosen such that it is larger than the input voltage range and output range. For instance, this application scales a signal of ± 0.5 V to ± 1.8 V. Setting the supply at ± 12 V is sufficient to accommodate this application.

10.2.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier using [Equation 1](#) and [Equation 2](#):

$$A_V = \frac{V_{OUT}}{V_{IN}} \quad (1)$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \quad (2)$$

Once the desired gain is determined, choose a value for R_I or R_F . Choosing a value in the kilohm range is desirable because the amplifier circuit uses currents in the milliamperage range. This ensures the part does not draw too much current. This example uses 10 k Ω for R_I which means 36 k Ω is used for R_F . This was determined by [Equation 3](#).

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

10.2.3 Application Curve

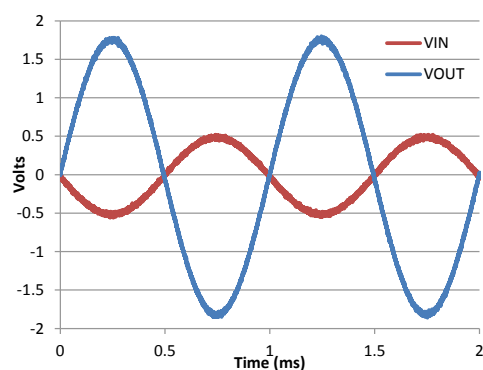


Figure 10-2. Input and Output Voltages of the Inverting Amplifier

11 Power Supply Recommendations

CAUTION

Supply voltages larger than specified in the recommended operating region can permanently damage the device (see [Section 7.1](#)).

Place 0.1- μ F bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see [Section 12](#).

12 Layout

12.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1- μ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping R_F and R_G close to the inverting input minimizes parasitic capacitance, as shown in [Section 12.2](#).
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

12.2 Layout Examples

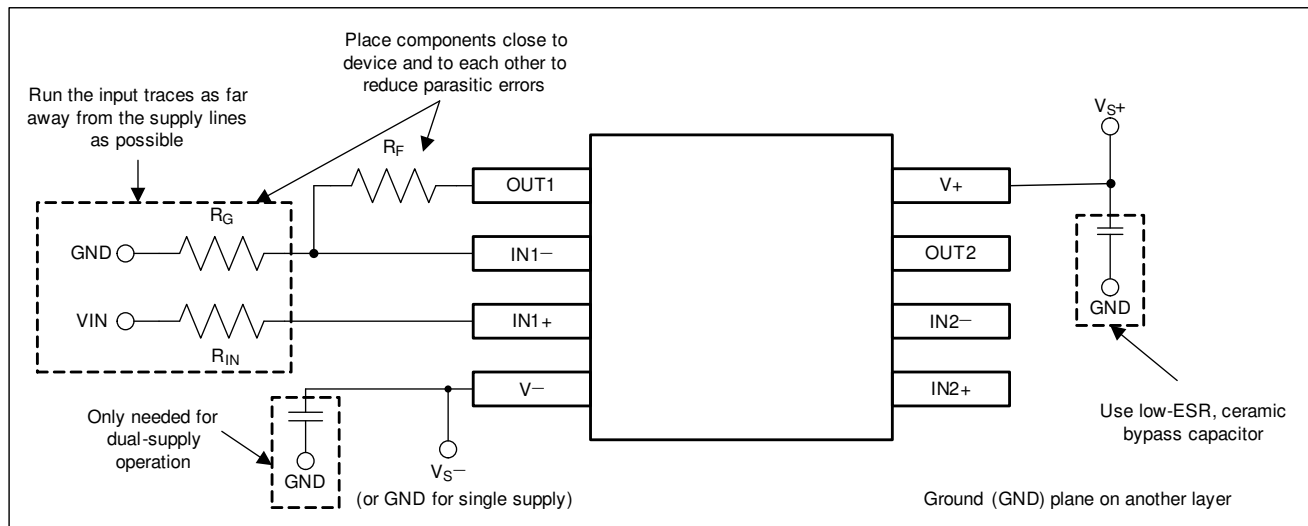


Figure 12-1. Operational Amplifier Board Layout for Noninverting Configuration

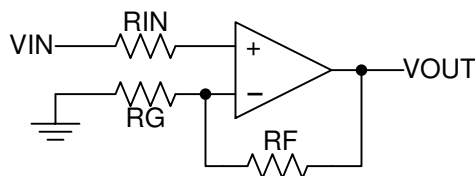


Figure 12-2. Operational Amplifier Schematic for Noninverting Configuration

13 Device and Documentation Support

13.1 Documentation Support

13.1.1 Related Documentation

For related documentation see the following:

Texas Instruments, [Application Design Guidelines for LM324/LM358 Devices application report](#)

13.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 13-1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM2904-Q1	Click here	Click here	Click here	Click here	Click here
LM2904B-Q1	Click here	Click here	Click here	Click here	Click here
LM2904BA-Q1	Click here	Click here	Click here	Click here	Click here

13.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

13.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

13.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

13.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser based versions of this data sheet, see the left-hand navigation pane.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2904AVQDRG4Q1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQDRG4Q1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQDRG4Q1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRG4Q1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRG4Q1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRG4Q1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRQ1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRQ1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904AVQPWRQ1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904AVQ
LM2904BAQDGKRQ1	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2EMB
LM2904BAQDGKRQ1.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2EMB
LM2904BAQDGKRQ1.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2EMB
LM2904BAQDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BA
LM2904BAQDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BA
LM2904BAQDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BA
LM2904BAQPWRQ1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	294BAQ
LM2904BAQPWRQ1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	294BAQ
LM2904BAQPWRQ1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	294BAQ
LM2904BQDGKRQ1	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	27ZB
LM2904BQDGKRQ1.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	27ZB
LM2904BQDGKRQ1.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	27ZB
LM2904BQDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ
LM2904BQDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ
LM2904BQDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ
LM2904BQPWRQ1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ
LM2904BQPWRQ1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2904BQPWRQ1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BQ
LM2904BTQDGKRQ1	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	4BTQ
LM2904BTQDGKRQ1.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	4BTQ
LM2904BTQDRQ1	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904TQ
LM2904BTQDRQ1.B	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904TQ
LM2904BTQPWRQ1	Active	Production	TSSOP (PW) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BT
LM2904BTQPWRQ1.B	Active	Production	TSSOP (PW) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904BT
LM2904QDRG4Q1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QDRG4Q1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QDRG4Q1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRG4Q1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRG4Q1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRG4Q1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRQ1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRQ1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904QPWRQ1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904Q1
LM2904VQDRG4Q1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQDRG4Q1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQDRG4Q1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ1
LM2904VQDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ1
LM2904VQDRQ1.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ1
LM2904VQPWRG4Q1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQPWRG4Q1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQPWRG4Q1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQPWRQ1	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQPWRQ1.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ
LM2904VQPWRQ1.B	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2904VQ

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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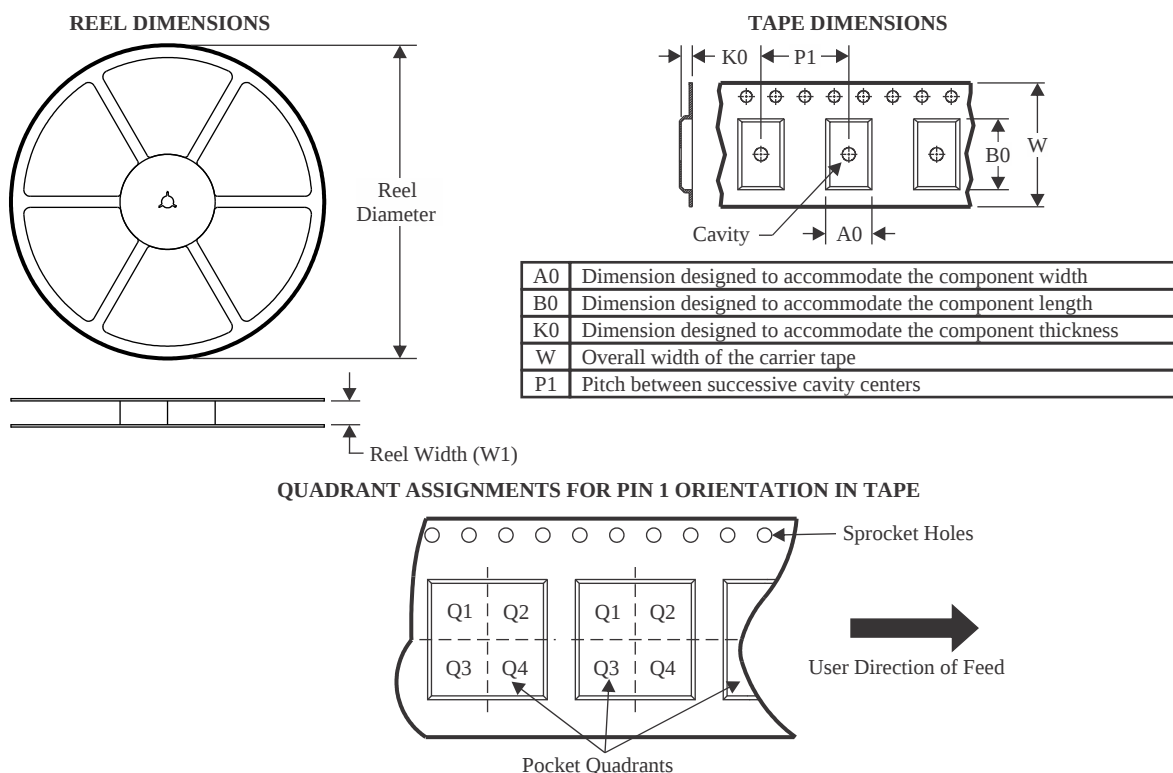
OTHER QUALIFIED VERSIONS OF LM2904-Q1, LM2904B-Q1, LM2904BA-Q1 :

- Catalog : [LM2904](#), [LM2904B](#), [LM2904BA](#)
- Enhanced Product : [LM2904-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2904AVQDRG4Q1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904AVQDRG4Q1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904AVQDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904AVQDRQ1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904AVQPWRG4Q1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904AVQPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904BAQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2904BAQDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904BAQPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904BQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2904BQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
LM2904BQDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904BQPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904BTQDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM2904BTQDRQ1	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904BTQPWRQ1	TSSOP	PW	8	3000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2904QDRG4Q1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904QDRG4Q1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904QDRQ1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904QPWRG4Q1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904QPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904VQDRG4Q1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904VQDRG4Q1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904VQDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LM2904VQDRQ1	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
LM2904VQPWRG4Q1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LM2904VQPWRQ1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

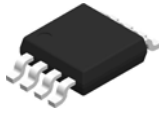


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2904AVQDRG4Q1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904AVQDRG4Q1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904AVQDRQ1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904AVQDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
LM2904AVQPWRG4Q1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904AVQPWRQ1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904BAQDGKRQ1	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2904BAQDRQ1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904BAQPWRQ1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904BQDGKRQ1	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2904BQDGKRQ1	VSSOP	DGK	8	2500	366.0	364.0	50.0
LM2904BQDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
LM2904BQPWRQ1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904BTQDGKRQ1	VSSOP	DGK	8	2500	353.0	353.0	32.0
LM2904BTQDRQ1	SOIC	D	8	3000	340.5	338.1	20.6
LM2904BTQPWRQ1	TSSOP	PW	8	3000	353.0	353.0	32.0
LM2904QDRG4Q1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904QDRG4Q1	SOIC	D	8	2500	340.5	338.1	20.6

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2904QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
LM2904QDRQ1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904QPWRG4Q1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904QPWRQ1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904VQDRG4Q1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904VQDRG4Q1	SOIC	D	8	2500	353.0	353.0	32.0
LM2904VQDRQ1	SOIC	D	8	2500	340.5	338.1	20.6
LM2904VQDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
LM2904VQPWRG4Q1	TSSOP	PW	8	2000	353.0	353.0	32.0
LM2904VQPWRQ1	TSSOP	PW	8	2000	353.0	353.0	32.0

DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

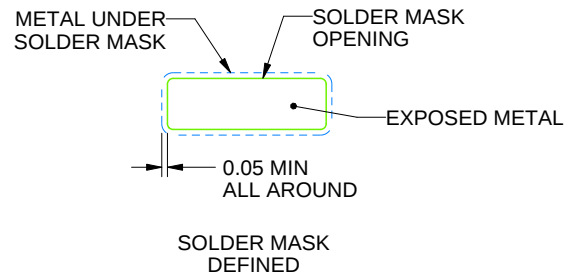
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

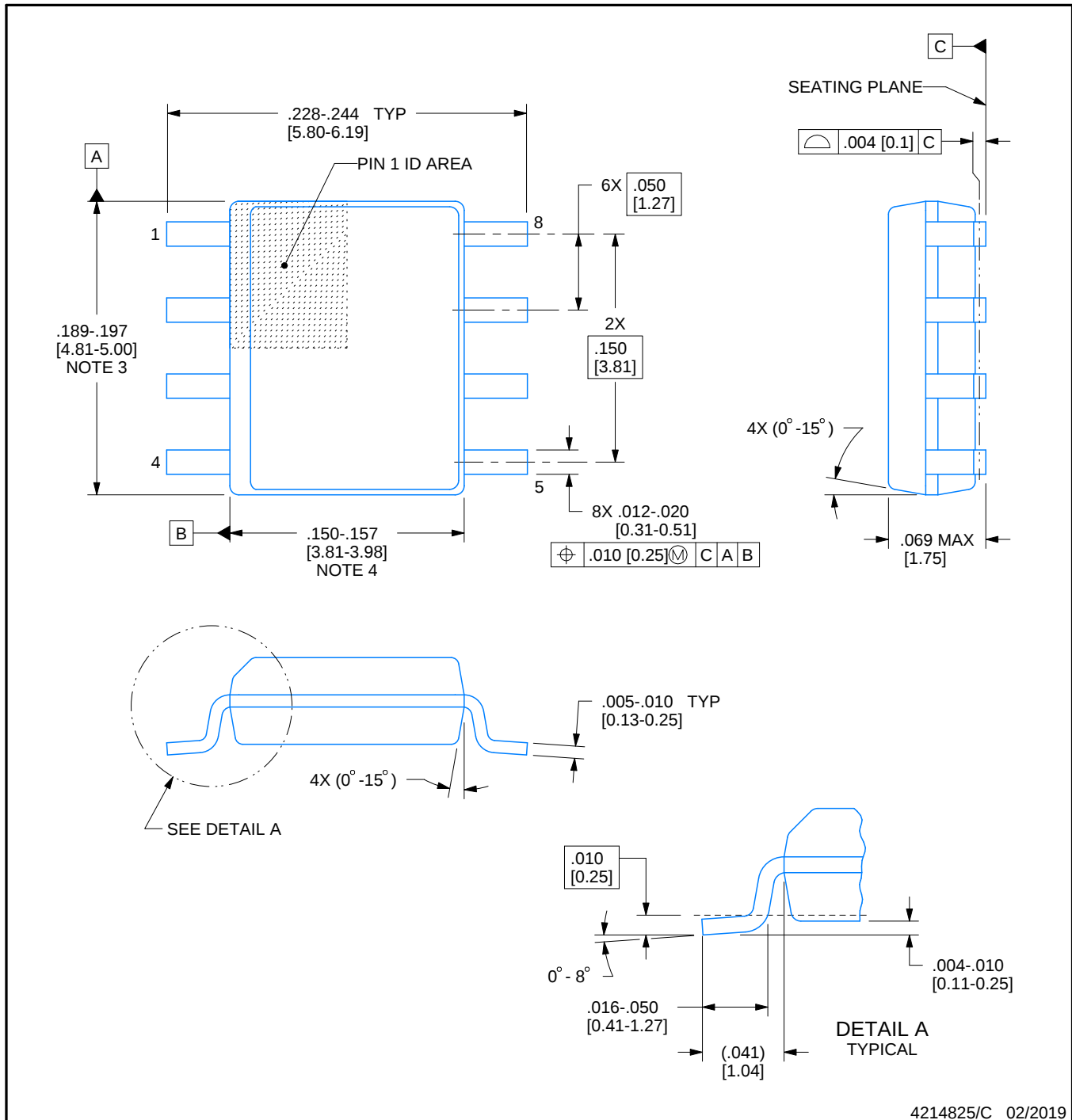


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

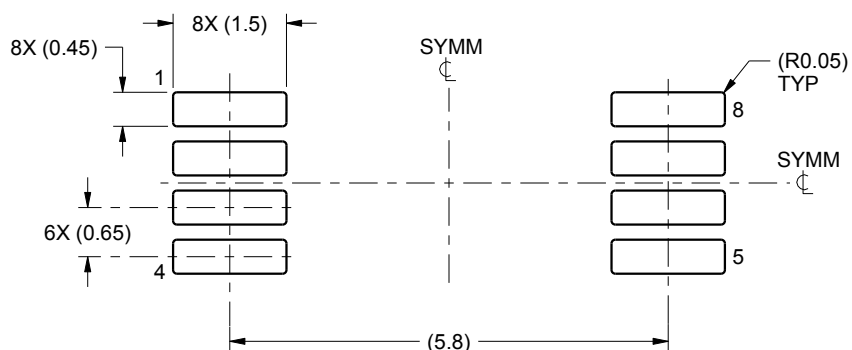
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

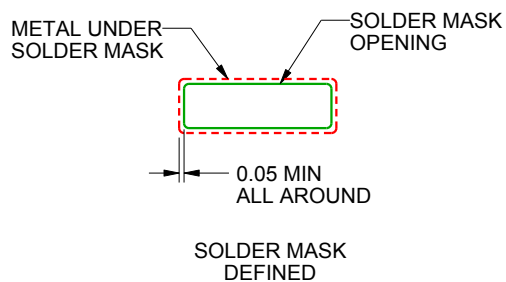
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

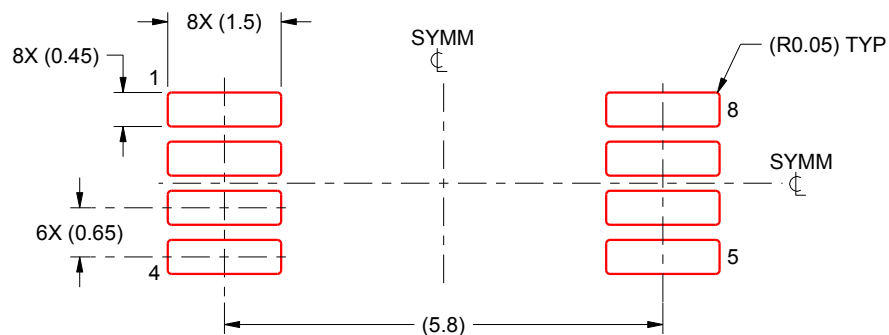
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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